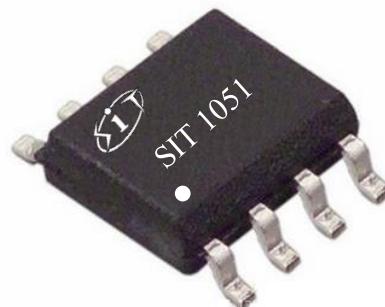


FEATURES

- Fully compatible with the ISO 11898 standard
- Thermally protected
- ±70V BUS Protection
- Transmit Data (TXD) dominant time-out function
- Silent receiving mode
- SIT1051T/E has a low-power shutdown mode
- SIT1051T/3 can be interfaced directly to microcontrollers with supply voltages from 3V to 5V
- Under-voltage protection
- Timing guaranteed for data rates up to 5 Mbit/s in the (CAN FD) fast phase
- High anti-electromagnetic interference ability
- Unpowered nodes do not interfere with the bus

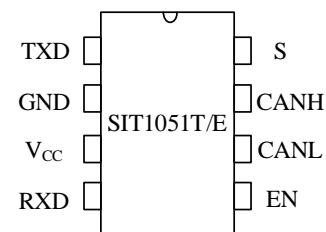
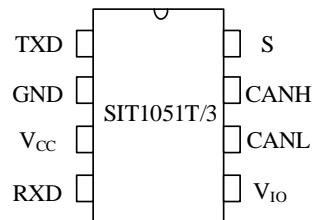
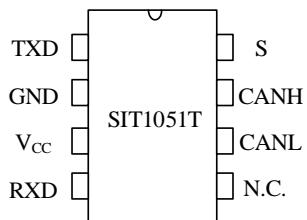
OUTLINE


Provide Green and Environmentally
Friendly Lead-free package

DESCRIPTION

SIT1051 is an interface chip used between the CAN protocol controller and the physical bus. It can be used in trucks, buses, cars, industrial control and other fields. It supports 5Mbps CAN With Flexible Data-Rate, and has a connection between the bus and the CAN protocol controller. The ability to perform differential signal transmission between.

PARAMETER	SYMBOL	CONDITION	MIN.	MAX.	UNIT
Supply voltage	V _{CC}		4.5	5.5	V
Maximum transmission rate	1/t _{bit}	Non-return to zero code	5		Mbaud
DC voltage on pin CANH and CANL	V _{can}		-70	+70	V
Bus differential voltage	V _{diff}		1.5	3.0	V
Virtual junction temperature	T _j		-40	150	°C

PIN CONFIGURATION

LIMITING VALUES

PARAMETER	SYMBOL	VALUE	UNIT
Supply voltage	V _{CC}	-0.3~+7	V
MCU side port	TXD, RXD, STB, V _{IO}	-0.3~+7	V
Bus side input voltage	CANL, CANH	-70~70	V
Bus differential breakdown voltage	V _{CANH-CANL}	-27~27	V
Transient voltage on pins CANH, CANL and SPLIT	V _{tr}	-200~+200	V
Storage temperature		-55~150	°C
Virtual junction temperature		-40~150	°C
Welding temperature range		300	°C

The maximum limit parameters means that exceeding these values may cause irreversible damage to the device. Under these conditions, it is not conducive to the normal operation of the device. The continuous operation of the device at the maximum allowable rating may affect the reliability of the device. The reference point for all voltages is ground.

PINNING

PIN	SYMBOL	DESCRIPTION
1	TXD	transmit data input
2	GND	ground supply
3	V _{CC}	supply voltage
4	RXD	receive data output; reads out data from the bus lines

5	V _{IO}	Transceiver I/O level conversion power supply voltage (SIT1051T/3 model)
	EN	Low-power shutdown mode selection, low level is shutdown mode (SIT1051T/E version)
	N.C.	No need connect, floating
6	CANL	LOW-level CAN bus line
7	CANH	HIGH-level CAN bus line
8	S	High speed and silent mode selection, low level is high speed

DRIVER ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
CANH dominant output voltage	V _{OH(D)}	TXD=0V, S=0V, R _L =60Ω, Fig.1, Fig.2	2.9	3.4	4.5	V
CANL dominant output voltage	V _{OL(D)}		0.8		1.5	V
Bus recessive output voltage	V _{O(R)}	TXD=V _{IO} , S=0V, R _L =60Ω, Fig.1, Fig.2	2	2.5	3	V
Bus dominant differential output voltage	V _{OD(D)}	TXD=0V, S=0V, RL=60Ω, Fig.1, Fig.2	1.5		3	V
Bus recessive differential output voltage	V _{OD(R)}	TXD=V _{IO} , S=0V, Fig.1, Fig.2	-0.012		0.012	V
		TXD=V _{IO} , S=0V, NO LOAD	-0.5		0.05	V
Transmitter dominant voltage symmetry	V _{dom(TX)sym}	V _{dom(TX)sym} =V _{CC} - V _{CANH} - V _{CANL}	-400		400	mV
Transmitter voltage symmetry	V _{TXsym}	V _{TXsym} =V _{CANH} + V _{CANL}	0.9V _{CC}		1.1V _{CC}	V
Common-mode output voltage	V _{OC}	S=0V, Fig.7	2	2.5	3	V
Peak-to-peak Common-mode output voltage	ΔV _{OC}			30		mV
Short-circuit output current	I _{os}	CANH=-12V, CANL=open, Fig.10	-105	-72		mA
		CANH=12V, CANL=open, Fig.10		0.36	1	mA
		CANL=-12V, CANH=open, Fig.10	-1	0.5		mA
		CANL=12V, CANH=open, Fig.10		71	105	mA
Recessive output current	I _{O(R)}	-27V<CANH<32V 0<V _{CC} <5.25V	-2.0		2.5	mA

(V_{CC}=5V±10% and Temp=T_{MIN}~T_{MAX} unless specified otherwise; typical in V_{CC}=+5V, V_{IO}=+5V and Temp=25°C)

DRIVER SWITCHING CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Propagation delay time, low-to-high-level output	t_{PLH}	S=0V, Fig.4		90		ns
Propagation delay time, low-to-high-level output	t_{PHL}			65		ns
Differential output signal rise time	t_r			45		ns
Differential output signal fall time	t_f			45		ns
TXD dominant time-out	t_{dom_TXD}	Fig.9	0.8	2	5	ms

($V_{CC}=5V\pm10\%$ and Temp= $T_{MIN}\sim T_{MAX}$ unless specified otherwise; typical in $V_{CC}=+5V$, $V_{IO}=+5V$ and Temp= $25^{\circ}C$)

RECEIVER ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Positive-going input threshold voltage	V_{IT+}	S=0V, Fig.5		800	900	mV
Negative-going input threshold voltage	V_{IT-}		500	650		
Hysteresis voltage ($V_{IT+} - V_{IT-}$)	V_{HYS}		50	120	200	
Power-off bus input current	$I_{(OFF)}$	CANH or CANL=5V, Other pin=0V	-5		5	μA
Input capacitance to ground, (CANH or CANL)	C_I			24		pF
Differential input capacitance	C_{ID}			12		pF
Input resistance, (CANH or CANL)	R_{IN}	TXD= V_{IO} , S=0V	9	15	28	k Ω
Differential input resistance	R_{ID}		19	30	52	k Ω



Input resistance matching	$R_{I_{match}}$	CANH=CANL	-2%		2%	
The range of common-mode voltage	V_{COM}		-30		30	V

($V_{CC}=5V\pm10\%$ and $\text{Temp}=T_{MIN}\sim T_{MAX}$ unless specified otherwise; typical in $V_{CC}=+5V$, $V_{IO}=+5V$ and $\text{Temp}=25^\circ C$)

RECEIVER SWITCHING CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Propagation delay time, low-to-high-level output	t_{PLH}	S=0V, Fig.6		65		ns
Propagation delay time, low-to-high-level output	t_{PHL}			60		ns
RXD signal rise time	t_r			10		ns
RXD signal fall time	t_f			10		ns

($V_{CC}=5V\pm10\%$ and $\text{Temp}=T_{MIN}\sim T_{MAX}$ unless specified otherwise; typical in $V_{CC}=+5V$, $V_{IO}=+5V$ and $\text{Temp}=25^\circ C$)

DEVICE SWITCHING CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Loop delay1, driver input to receiver output, Recessive to Dominant	$T_{d(LOOP1)}$	S=0V, Fig.8		90	220	ns
Loop delay 2, driver input to receiver output, Dominant to Recessive	$T_{d(LOOP2)}$			100	220	ns
Bit time of BUS output pin	$t_{bit(BUS)}$	$t_{bit(TXD)}=500\text{ns}$	435		530	ns
		$t_{bit(TXD)}=200\text{ns}$	155		210	ns
Bit time of RXD output pin	$t_{bit(RXD)}$	$t_{bit(TXD)}=500\text{ns}$	400		550	ns
		$t_{bit(TXD)}=200\text{ns}$	120		220	ns

($V_{CC}=5V\pm10\%$ and $\text{Temp}=T_{MIN}\sim T_{MAX}$ unless specified otherwise; typical in $V_{CC}=+5V$, $V_{IO}=+5V$ and $\text{Temp}=25^\circ C$)



OVER TEMPERATURE PROTECTION

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Shutdown junction temperature	$T_{j(sd)}$			190		°C

(V_{CC}=5V±10% and Temp=T_{MIN}~T_{MAX} unless specified otherwise; typical in V_{CC}=+5V, V_{IO}=+5V and Temp=25°C)

UNDER-VOLATAGE PROTECTION

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
V _{CC} under-voltage protection	V _{uvd_VCC}		3.5		4.5	V
V _{IO} under-voltage protection	V _{uvd_VIO}		1.5		2.5	V

(V_{CC}=5V±10% and Temp=T_{MIN}~T_{MAX} unless specified otherwise; typical in V_{CC}=+5V, V_{IO}=+5V and Temp=25°C)

TXD PIN CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
HIGH-level input current	I _{IH} (TXD)	TXD=V _{IO}	-5		5	μA
LOW-level input current	I _{IL} (TXD)	TXD=0V	-260	-150	-30	μA
When V _{IO} =0V, current on TXD pin	I _{O(off)}	V _{CC} =V _{IO} =0V, TXD=V _{IO}	-1		1	μA
HIGH-level input voltage	V _{IH}		0.7V _{IO} ^①		V _{IO} ^① +0.3	V
LOW-level input voltage	V _{IL}		-0.3		0.3V _{IO} ^①	V
Open voltage on TXD pin	TXD _O			H		logic

(V_{CC}=5V±10% and Temp=T_{MIN}~T_{MAX} unless specified otherwise; typical in V_{CC}=+5V, V_{IO}=+5V and Temp=25°C)



STB PIN CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
HIGH-level input current	I _{IH(S)}	S=V _{IO}	1	4	10	μA
LOW-level input current	I _{IL(S)}	S=0V	-1		1	μA
HIGH-level input voltage	V _{IH}		0.7V _{IO} ^①		V _{IO} ^① +0.3	V
LOW-level input voltage	V _{IL}		-0.3		0.3V _{IO} ^①	V
Open voltage on STB pin	S _O		L			logic

(① SIT1051T model V_{IO}=V_{CC}(V_{CC}=5V±10% and Temp=T_{MIN}~T_{MAX} unless specified otherwise; typical in V_{CC}=+5V, V_{IO}=+5V and Temp=25°C)

RXD PIN CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
HIGH-level input current	I _{OH(RXD)}	V _{IO} =V _{CC} , RXD=V _{IO} -0.4V	-8	-3	-1	mA
LOW-level input current	I _{OL(RXD)}	RXD=0.4V, bus dominant	2	5	12	mA
When V _{CC} =0V, current on RXD pin	I _{O(off)}	V _{CC} =V _{IO} =0V, RXD=V _{IO}	-1		1	μA

(V_{CC}=5V±10% and Temp=T_{MIN}~T_{MAX} unless specified otherwise; typical in V_{CC}=+5V, V_{IO}=+5V and Temp=25°C)

EN PIN CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
EN HIGH-level input current	I _{EH(EN)}	EN=V _{CC}	1	4	10	μA
EN LOW-level input current	I _{EL(EN)}	EN=0V	-1		1	μA
EN HIGH-level input voltage	V _{EH}		0.7V _{CC}		V _{CC} +0.3	V



EN LOW-level input voltage	V _{IL}		-0.3		0.3V _{CC}	V
EN open voltage	E _{NO}		L			logic

(V_{CC}=5V±10% and Temp=T_{MIN}~T_{MAX} unless specified otherwise; typical in V_{CC}=+5V, V_{IO}=+5V and Temp=25°C)**SUPPLY CURRENT**

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
V _{CC} supply current	Normal dominant	I _{CC_D}	bus dominant		45	mA
	Normal recessive	I _{CC_R}	bus recessive		5	mA
	Silent	I _{CC_S}	S=TXD=V _{IO}		1	mA
	Shutdown	I _{CC_EN}	EN=0V or open (SIT1051T/E model)		0.5	μA
V _{IO} supply current	Normal or Silent mode dominant	I _{IO_D}	RXD open TXD=0V		350	μA
	Normal or Silent mode recessive	I _{IO_R}	RXD open, TXD=V _{IO}		80	μA

(V_{CC}=5V±10% and Temp=T_{MIN}~T_{MAX} unless specified otherwise; typical in V_{CC}=+5V, V_{IO}=+5V and Temp=25°C)**ESD PERFORMANCE**

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
CAN bus pin contact discharge model (IEC)	V _{ESD_IEC}	IEC 61000-4-2: Contact discharge (CANH, CANL)	-4		+4	kV
CAN bus pin human body discharge model (HBM)	V _{ESD_HBM}		-8		+8	kV
Component charging model (CDM)	V _{CDM}		-750		+750	V

FUNCTION TABLE
Table1.CAN TRANSCEIVER TRUTH TABLE

TXD⁽¹⁾	S⁽¹⁾	CANH⁽¹⁾	CANL⁽¹⁾	BUS STATE	RXD⁽¹⁾
L	L or Open	H	L	Dominate	L
H or Open	L or Open	0.5V _{CC}	0.5V _{CC}	Recessive	H
X	H	0.5V _{CC}	0.5V _{CC}	Recessive	H

(1) H=high level; L=low level; X=irrelevant

Table 2. RECEIVER FUNCTION TABLE

V_{ID}=CANH-CANL	RXD⁽¹⁾	BUS
V _{ID} ≥0.9V	L	Dominate
0.5<V _{ID} <0.9V	?	?
V _{ID} ≤0.5V	H	Recessive
Open	H	Recessive

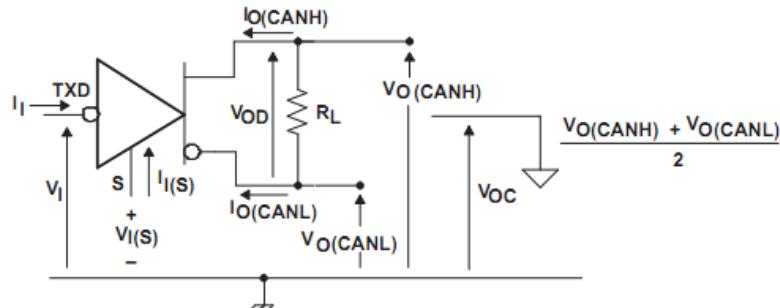
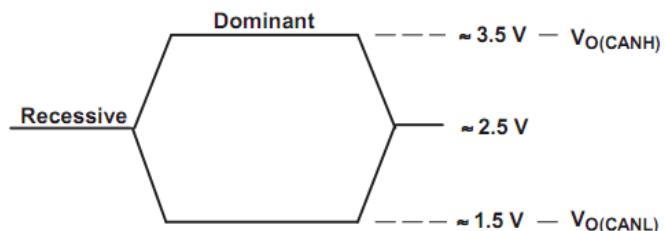
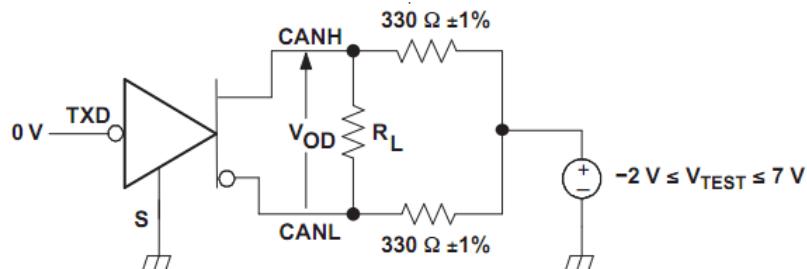
(1) H=high level; L=low level; ? =uncertain

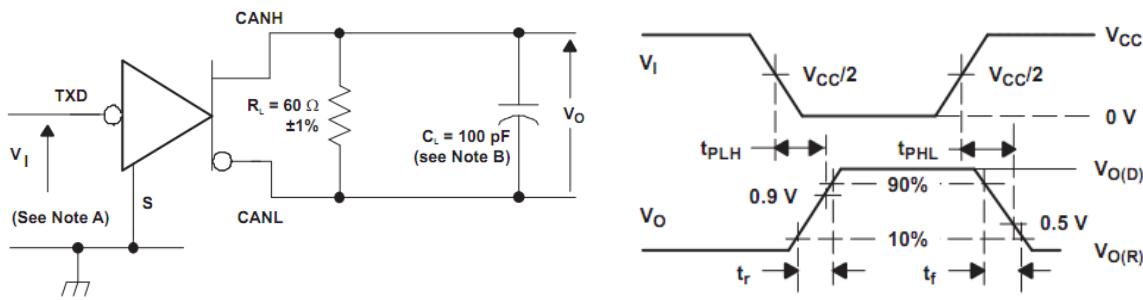
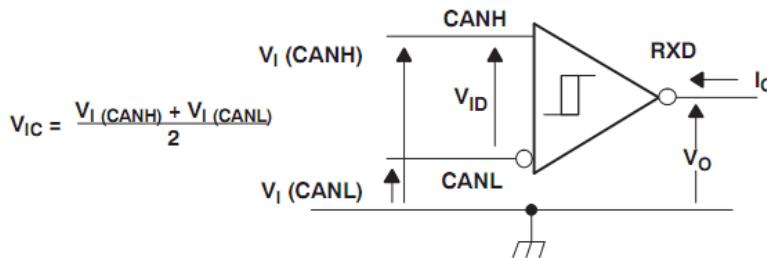
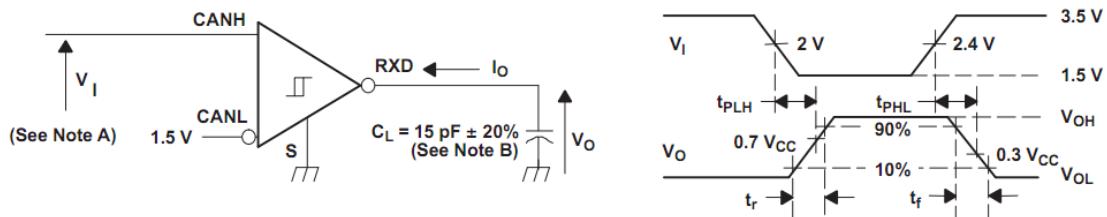
Table 3. UNDERVOLTAGE PROTECTION STATUS TABLE

V_{CC}	V_{IO}⁽¹⁾	BUS	BUS OUTPUT⁽²⁾	RXD⁽²⁾
V _{CC} >V _{uvd_VCC}	V _{IO} >V _{uvd_VIO}	normal	According to S and TXD	Follow the bus
V _{CC} <V _{uvd_VCC}	V _{IO} >V _{uvd_VIO}	Protected status	Z	H
V _{CC} >V _{uvd_VCC}	V _{IO} <V _{uvd_VIO}	Protected status	Z	H
V _{CC} <V _{uvd_VCC}	V _{IO} <V _{uvd_VIO}	Protected status	Z	H

(1) SIT1051T/3 version only;

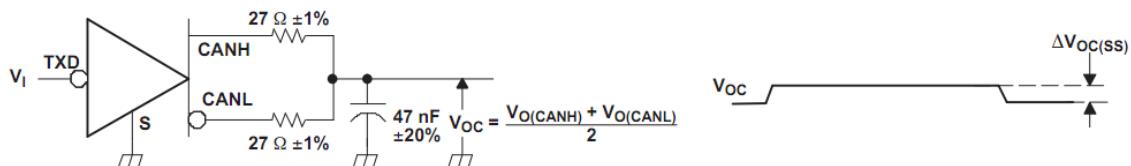
(2) H=high level; Z=high impedance;

TEST CIRCUIT

Fig.1 Driver Voltage, Current, and Test Definition

Fig.2 Bus Logic State Voltage Definition

Fig.3 Driver Vod Test Circuit


Fig.4 Driver Test Circuit and Waveform

Fig.5 Receiver Voltage and Current Definition


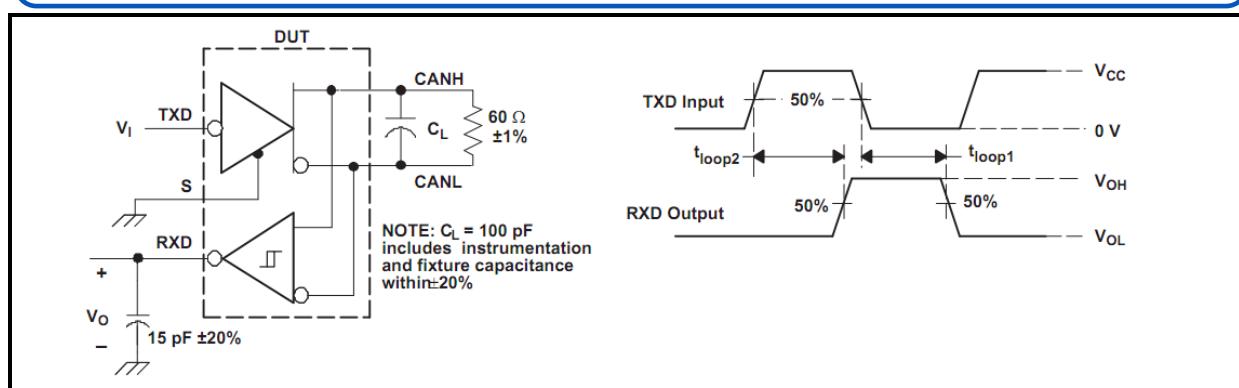
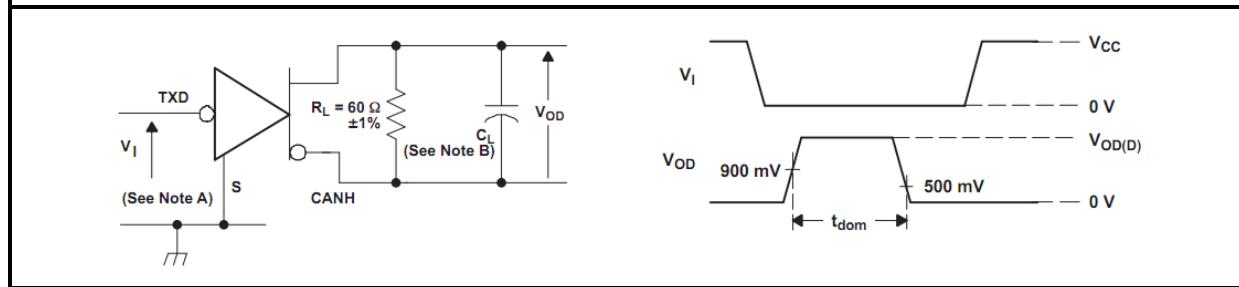
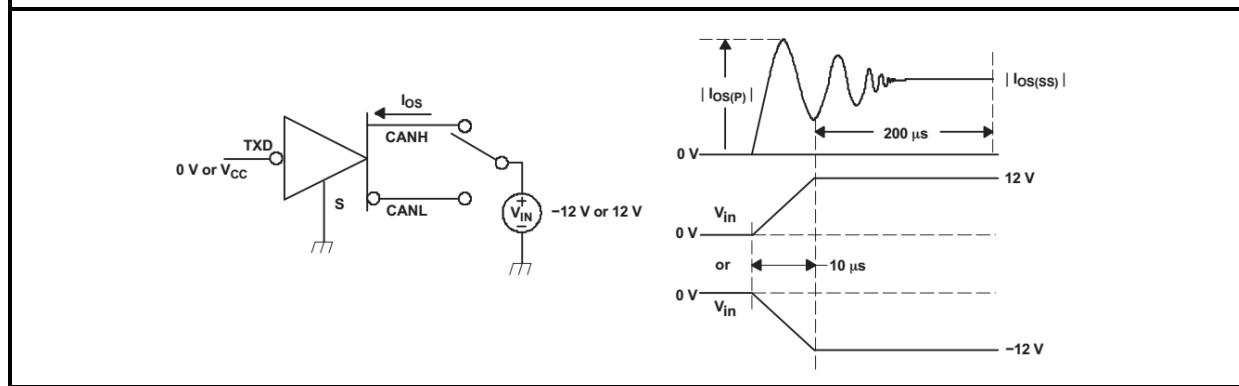
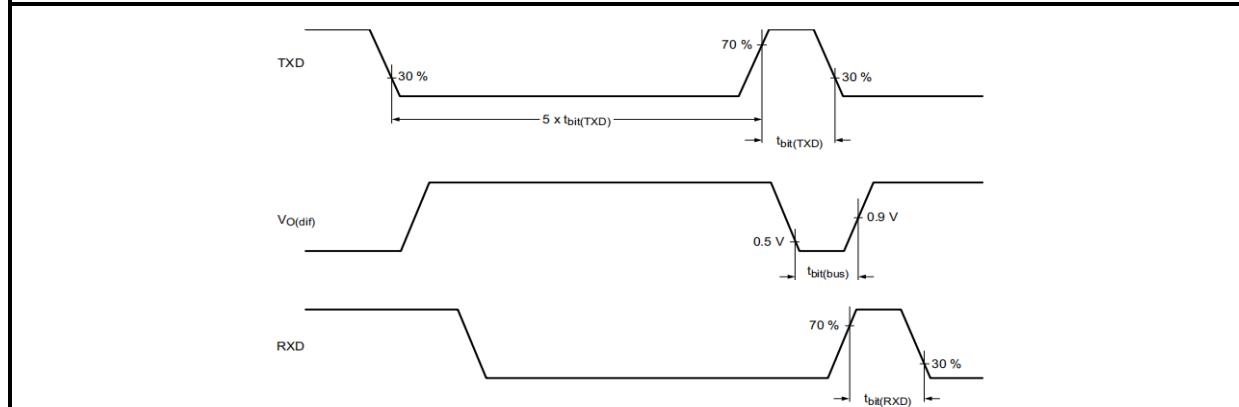
A. The input pulse is supplied by a generator having the following characteristics: PRR $\leq 125 \text{ kHz}$, 50% duty cycle, $t_r \leq 6 \text{ ns}$, $t_f \leq 6 \text{ ns}$, $Z_0 = 50 \Omega$.

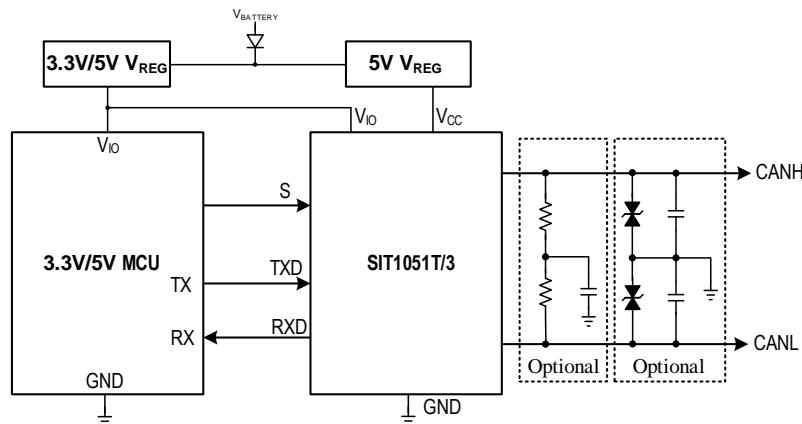
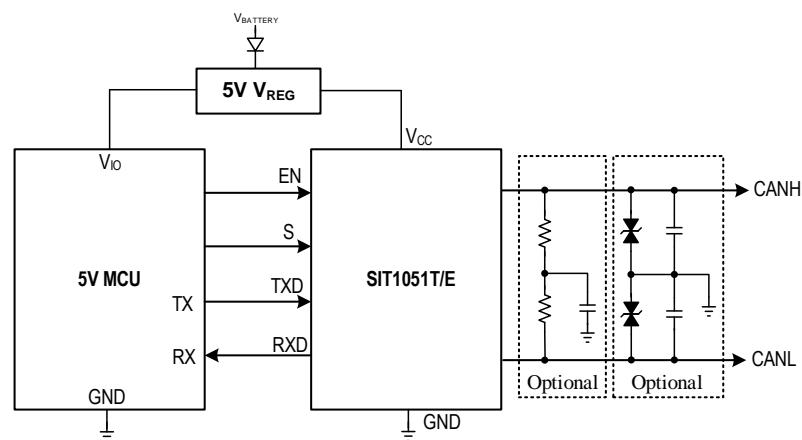
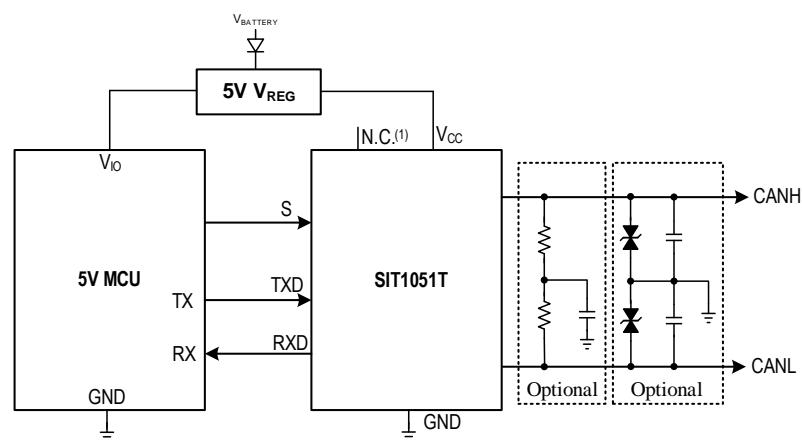
B. C_L includes instrumentation and fixture capacitance within $\pm 20\%$.

Fig.6 Receiver Test Circuit and Waveform


All V_I input pulses are from 0 V to V_{CC} and supplied by a generator having the following characteristics: t_r or $t_f \leq 6 \text{ ns}$. Pulse Repetition Rate (PRR) = 125 kHz , 50% duty cycle.

Fig.7 Peak-to-Peak Common Mode Output Voltage Test and Waveform


Fig.8 t_{LOOP} Test Circuit and Waveform

Fig.9 Dominant Time-Out Test Circuit and Waveform

Fig.10 Driver Short-Circuit Current Test Circuit and Waveform

Fig.11 $t_{bit(RXD)}$ test circuit and waveform

APPLICATION DIAGRAMS

Fig.12 Typical application of the SIT1051T/3

Fig.13 Typical application of the SIT1051T/E

Fig.14 Typical application of the SIT1051T

(1) It is recommended to float the N.C. pin.

ADDITIONAL DESCRIPTION

1 Sketch

The SIT1051 is the interface between the Controller Area Network (CAN) protocol controller and the physical bus, and can be applied to the fields of trucks, buses, cars, industrial control etc. Support 5Mbps CAN With Flexible Data-Rate. The device provides differential transmit capability to the bus and differential receive capability to the CAN controller, and fully compatible with the ISO 11898 standard.

2 Current protection

A current-limiting circuit protects the transmitter output stage from damage caused by accidental short-circuit to either positive or negative supply voltage, although power dissipation increases during this fault condition.

3 Over temperature protection

SIT1051 has the function of over temperature protection. After the over temperature protection is triggered, the current of the driving stage will be reduced, because the driving tube is the main energy consuming part. The current reduction can reduce the power consumption and thus reduce the chip temperature. At the same time, other parts of the chip still work normally.

4 Under-voltage protection

The SIT1051 power supply pin has an under-voltage detection function, which can put the device in a protected mode. This protects the bus when V_{CC} is lower than V_{uvd_VCC} or V_{IO} is lower than V_{uvd_VIO} .

5 Operating modes

The SIT1051 provides two modes of operation which are selectable via pin S: High-speed mode and silent mode.

The high-speed mode is the normal operating mode and is selected by connecting pin S to ground or open. Both the CAN driver and the receiver can operate normally and CAN communication is carried out in both directions.

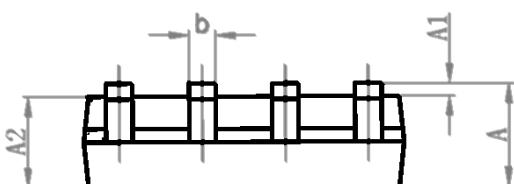
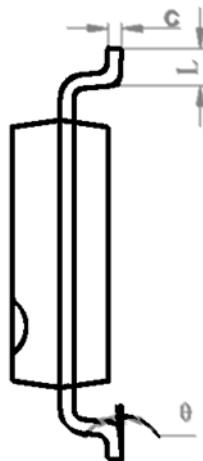
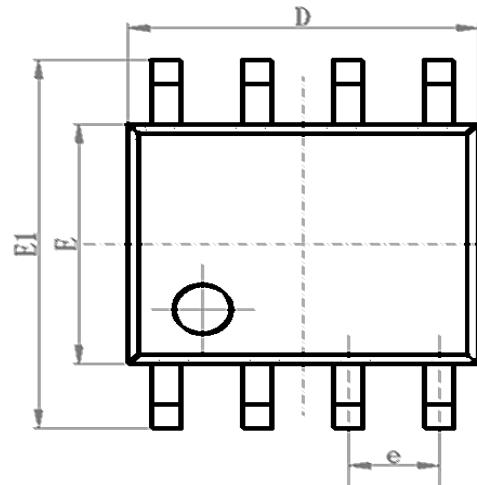
Set pin S to a high level to activate the mute mode. The CAN driver will shut down and the receiver will continue to work.

6 TXD dominant time-out function

In high-speed mode, if the low-level duration on pin TXD exceeds the internal timer value (t_{dom_BUS}), the transmitter will be disabled and drive the bus into a recessive state. It can prevent the pin TXD from being forced to a permanent low level due to a hardware or software application failure, causing the bus line to be driven to a permanent dominant state (blocking all network communications). A rising edge signal on pin TXD can be reset.

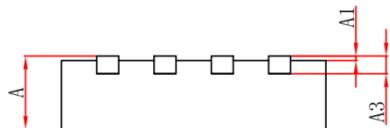
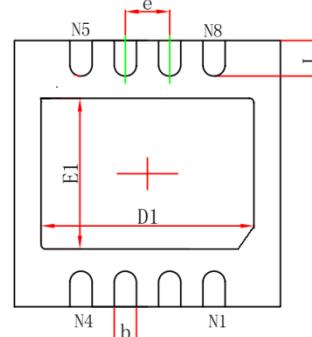
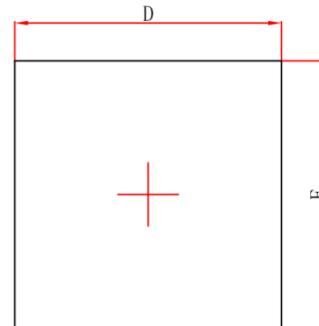
SOP8 DIMENSIONS
PACKAGE SIZE

SYMBOL	MIN./mm	TYP./mm	MAX./mm
A	1.40	-	1.80
A1	0.10	-	0.25
A2	1.30	1.40	1.50
b	0.38	-	0.51
D	4.80	4.90	5.00
E	3.80	3.90	4.00
E1	5.80	6.00	6.20
e		1.27BSC	
L	0.40	0.60	0.80
c	0.20	-	0.25
θ	0°	-	8°



DFN3*3-8 /HVSON8 DIMENSIONS
PACKAGE SIZE

SYMBOL	MIN./mm	TYP./mm	MAX./mm
A	0.70		0.80
A1	0.00	0.02	0.05
A3	0.203 REF		
D	2.90	3.00	3.10
E	2.90	3.00	3.10
D1	2.35	2.3	2.55
E1	1.55	1.65	1.75
b	0.2	0.25	0.33
e	0.65 TYP		
L	0.35		0.45


ORDERING INFORMATION

TYPE NUMBER	TEMPERATURE	PACKAGE
SIT1051T	-40°C~150°C	SOP8
SIT1051T/E	-40°C~150°C	SOP8
SIT1051T/3	-40°C~150°C	SOP8
SIT1051TK/3	-40°C~150°C	HVSON8 / DFN3*3-8, Small Outline, Leadless

SOP8 package is 2500 pieces/disc. HVSON8 / DFN3*3-8 package is 5000 pieces/disc.

Important statement

SIT reserves the right to change the above-mentioned information without prior notice.